

20V to 250V Driver for High Power PIN Diode Switches

Rev. V1

Features

- 20 V to 250 V Back Bias in Off State
- 200 mA Series Diode Bias Current at +25°C
- 50 mA Shunt Diode Bias Current at +25°C
- Propagation Delay less than 8 µs
- Low Quiescent Current Consumption
- 3 V or 5 V CMOS Logic Control
- 7 mm QFN-16LD Package
- Tape and Reel Packaging Available
- RoHS* Compliant and 260°C Reflow Compatible

Description

The MADR-010574 switch driver is designed to work with M/A-COM Technology Solutions high power and high voltage PIN diodes. This driver consists of two independently controlled drivers which are able to provide 200 mA series / 50 mA shunt current to a series/shunt, series/shunt SPDT PIN diode switch. The back bias voltage is configurable from 20 V to 250 V. High voltage level shifters are integrated so that it can be easily controlled by 3 V or 5 V CMOS logic. While consuming low quiescent current, this driver has a typical delay of less than 8 µs when driving 220 pF capacitor load. If needed, the switching speed can be improved by consuming more quiescent power.

This driver is packaged in a lead free 7 mm PQFN-16LD package and is available in tape and reel packaging for high volume applications.

Ordering Information

1

volume is not guaranteed.

Part Number	Package
MADR-010574-000100	Bulk Packaging
MADR-010574-0001TR	1000 piece Reel
MADR-010574-001SMB	Sample Board with Driver & MA4P504-1072T Diodes

Functional Schematic



Pin Configuration¹

Pin No.	Pin Name	Description
1	SH1	Shunt1
2	C1	Control Logic 1
3	I _{BIAS}	Bias Voltage
4	SER1	Series1
5	N/C ²	No Connection
6	GND	Ground
7	GND	Ground
8	N/C ²	No Connection
9	SH2	Shunt2
10	V _{cc}	Control Voltage
11	C2	Control Logic 2
12	SER2	Series2
13	GND	Ground
14	N/C ²	No Connection
15	N/C ²	No Connection
16	V _{DD}	Drain Voltage
17	Paddle	Ground

1. The paddle of the QFN package should be tied to ground.

 N/C pins (except Pin 15) can be grounded. The clearance from high voltage pins should be at least 0.8 mm. Pin 15 must be left open.

* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

been fixed. Engineering samples and/or test data may be available. Commitment to produce in

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300 • Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
- Visit www.macom.com for additional data sheets and product information.

ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has



20V to 250V Driver for High Power PIN Diode Switches

Rev. V1

Recommended Operating Conditions

Parameter	Test Conditions U		Min.	Тур.	Max.
V _{cc}	Nominal V _{CC} = 3.3 V Nominal V _{CC} = 5.0 V	V	3.0 4.5	3.3 5.0	3.6 5.5
V _{DD}	—	V	20		250
Control1, Control2 ³	Logic "0" Logic "1"	V	0.0 0.7 × V _{CC}	0.0 V _{CC}	$0.3 \times V_{CC}$ V_{CC}
Series1/Series2 Sinking Current ⁴	-40°C +25°C +85°C	mA	_	—	300 200 150
Shunt1/Shunt2 Sinking Current ⁴	-40°C +25°C +85°C	mA	_	_	65 55 50
I _{BIAS} ^{5,6}	+25°C	μA	2	6	150
Operating Temperature	_	°C	-40	+25	+85

3. Unused Controls should be either grounded or connected to V_{CC} . They should never be left open.

4. Refer to "Application Circuit: Driving SPDT Switch with MA4P504-1072T Pin Diodes" for configuration of diode bias currents.

 This sinking bias current is necessary for normal driver operation. The easiest way is to connect a 0402 resistor R_{BIAS} between Pin V_{CC} and Pin I_{BIAS}. Then I_{BIAS} can be calculated by: I_{BIAS} = (V_{CC}-0.6)/(500+R_{BIAS})

 Refer to graph "Typ. Ton Driving 220 pF Caps vs. IBIAS" on page 3 and the chart "Typ. IDD vs. IBIAS at 25°C" on page 4 for the tradeoff between switching speed and power consumption.

Absolute Maximum Ratings 7,8

Parameter	Absolute Maximum			
V _{CC}	-0.5 V to +7 V			
V _{DD}	-0.5 V to 275 V			
C1, C2 (Logic)	-0.5 V to 7 V			
Series1/Series2 Sinking Current -40°C +25°C +85°C	550 mA 450 mA 350 mA			
Shunt1/Shunt2 Sinking Current -40°C +25°C +85°C	150 mA 150 mA 100 mA			
Series/Shunt Outputs Sourcing Current	25 mA			
I _{BIAS}	500 µA			
ESD HBM Rating	>1kV			
Operating Temperature	-40 to +125°C			
Storage Temperature	-55 to +150°C			

7. M/A-COM Technology Solutions does not recommend sustained operation near these survivability limits.

8. Exceeding any one or combination of these limits may cause permanent damage to this device.

Truth Table ⁹

C1	C2	Series1	Shunt1	Series2	Shunt2
0	0	Low	High	Low	High
0	1	Low	High	High	Low
1	0	High	Low	Low	High
1	1	High	Low	High	Low

9. The actual voltage levels for "Low" and "High" are dependent on the current load to the driver. They can be estimated from the driver on resistance.

Powering On/Off Sequence:

 V_{DD} should be turned on after $V_{\text{CC}},$ and the rise time of V_{DD} should be slower than 2.5 $\mu s.$ When powering off, V_{DD} should be turned off before $V_{\text{CC}}.$

- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
- Visit www.macom.com for additional data sheets and product information.

M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

2

ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM has under develop ment. Performance is based on accinenting the consideration or trained. Machanical with a ment performance is based on accinenting to the consideration of the constraint of the con

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

North America Tel: 800.366.2266 / Fax: 978.366.2266



20V to 250V Driver for High Power PIN Diode Switches

Rev. V1

Electrical Specifications: $T_A = +25^{\circ}C$, $V_{CC} = 3.3 V$, $V_{DD} = 250 V$, $I_{BIAS} = 6 \mu A^{10}$

Parameter	Test Conditions	Unit	Min.	Тур.	Max.
Quiescent Supply Currents	V _{CC} (3.3 V) ¹¹ V _{DD} (250 V)	μA	_	6 25	10 37
Control Input Leakage Current	—	μA		_	1
Series Pull-down FET On Resistance	200 mA Load	Ω		9	11.4
Shunt Pull-down FET On Resistance	50 mA Load	Ω		26	30
Switching Speed Driving 220pF Caps: Series ¹² T _{ON} T _{OFF} Tr Tf	50% CTL to 95% Voltage 50% CTL to 5% Voltage 10% - 90% 90% - 10%	μs		6.2 0.22 5.1 0.1	
Switching Speed Driving 220pF Caps: Shunt ¹² $$T_{\rm ON}$$ $$T_{\rm OFF}$$ $$Tr$$ $$Tf$$	50% CTL to 95% Voltage 50% CTL to 5% Voltage 10% - 90% 90% - 10%	μs		3.1 0.2 2.6 0.08	

10. The parameters were measured with 500 k Ω R_{BIAS} connecting between pin V_{CC} and pin I_{BIAS}

11. I_{BIAS} is included in the quiescent V_{CC} current due to the bias configuration.

12. Switching parameters were measured driving 220 pF capacitors with no current load. Controls C1 and C2 were tied together. It will be faster when C2 is inverted from C1, which is case driving a SPDT switch.



Typ. Ton Driving 220pF Caps vs IBIAS VCC = 3.3V, VDD = 250V, 25°C



volume is not guaranteed.

ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has

been fixed. Engineering samples and/or test data may be available. Commitment to produce in

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macom.com for additional data sheets and product information.



20V to 250V Driver for High Power PIN Diode Switches

Rev. V1

Performance Driving M/A-COM MA4P504-1072T PIN Diode SPDT Switch ¹³











⁴

ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.



Typ. Toff (50% Ctl to 10% RF) vs. VDD VCC=3.3V, IBIAS=6μA



 The switch is a series/shunt, series/shunt SPDT switch using four M/A-COM MA4P504-1072T PIN diodes. Schematic is on next page. Switching parameters were measured with 500 MHz 20W CW RF signal.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macom.com for additional data sheets and product information.



20V to 250V Driver for High Power PIN Diode Switches

Application Circuit: Driving SPDT Switch with MA4P504-1072T PIN Diodes ¹⁴



14. This is the schematic of MADR-010547-001SMB. The frequency range for this application circuit is 200 MHz to 500 MHz. The bias current for the series diodes is 200 mA. The bias current for the shunt diodes is 50 mA. The recommended inductors are Coil Craft 0603LS-181XJLB for both current and frequency considerations. For different frequency applications, both capacitors and inductors should be adjusted accordingly.

volume is not guaranteed.

been fixed. Engineering samples and/or test data may be available. Commitment to produce in

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macom.com for additional data sheets and product information.

ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has



20V to 250V Driver for High Power PIN Diode Switches

Rev. V1

Recommended PCB



Parts List

Part	Value	Size	
C5	0.01 µF, 500 V	0805	
C6 - C12	100 pF, 500 V 0805		
C13 - C15	0.1 µF, 16 V	0402	
L1 - L8	180 nH	0603	
R1	1.5 Ω, 1 W 2512		
R2	15 Ω, 0.5 W	1206	
R3	499 KΩ, 1/16 W	0402	
D1 - D4	MA4P504-1072		

Footprint



ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY**: Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has

been fixed. Engineering samples and/or test data may be available. Commitment to produce in

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300 • Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macom.com for additional data sheets and product information.

M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

6

volume is not guaranteed.



20V to 250V Driver for High Power PIN Diode Switches

Rev. V1

Lead Free 7mm PQFN-16LD [†]



[†] This is not a JEDEC standard package. Please refer to Application Note for footprint and lead-free solder reflow recommendations.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Silicon Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

volume is not guaranteed.

ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has

been fixed. Engineering samples and/or test data may be available. Commitment to produce in

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macom.com for additional data sheets and product information.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный) **Факс:** 8 (812) 320-02-42 **Электронная почта:** <u>org@eplast1.ru</u> **Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.